

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	52958	semiconductor and (nonvolatile or (non adj volatile))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 12:56
L2	6748	1 and floating and control and gate and electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 12:57
L3	1814	2 and (trench\$2 or groove or recess\$2)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 12:57
L4	1763	3 and (dielectric or insulat\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/05 12:58